

### **ES3AB THRU ES3JB**

### Super Fast Recovery Rectifier Diode

### **Features**

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Super fast reverse recovery time
- High forward surge capability
- Meets MSL level 1, per J-STD-020,LF maximum peak of 260 °C



# **←**

### **Typical Application**

For use in high frequency rectification of power supply, inverters, converters, and freewheeling diodes for consumer and telecommunication.

### **Mechanical Data**

- Package: DO-214AA(SMB)
   Molding compound meets UL 94 V-0 flammability rating,RoHS-compliant
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity: Cathode line denotes the cathode end

### ■ Maximum Ratings (Ta=25°C Unless otherwise specified)

DADAMETED	Symbol	Unit	Conditions	ES3							
PARAMETER			Conditions	AB	ВВ	СВ	DB	FB	GB	НВ	JB
Repetitive Peak Reverse Voltage	VRRM	V		50	100	150	200	300	400	500	600
Average Forward Current	lF(AV)	Α	60Hz Half-sine wave, Resistance load, TL=100℃	3.0							
Surge(Nonrepetitive)Forward Current	IFSM	Α	60HZ Half-sine wave, 1 cycle, Ta=25℃	90							
Storage Temperature	Tstg	°C		-55 ~ +150							
Junction Temperature	Tj	°C		-55 ~ +150							

### Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	Symbol	Unit	Condition	ES3								
PARAMETER			Conditions		AB	ВВ	СВ	DB	FB	GB	НВ	JB
Peak Forward Voltage	V <sub>FM</sub>	V	I <sub>F</sub> =3.0	0.95			1.3		1.7			
Peak Reverse Current	IRRM1		V <sub>RM</sub> =V <sub>RRM</sub>	Ta=25℃	10							
	IRRM2	μA	VRM-VRRM	Ta=125℃	500							
Maximum reverse recovery	Ter	no	I <sub>F</sub> =0.5A,I <sub>R</sub> =1.0A,I <sub>rr</sub> =0.25A		25							
time	Trr	ns			35							
Thermal Resistance(Typical)	<b>R</b> өJ-A	°C/W	Between junction and ambient		471)							
	Rej-L		Between junction ar	121)								

Notes:

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<sup>1)</sup> Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas



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### ■ Characteristics (Typical)

### FIG1: Forward Current Derating Curve FIG2:Maximum Non-Repetitive Forward Surge Current 150 (A) 3.0 125 TL=75°C 2.5 8.3ms Single Half Sine Wave 100 2.0 75 1.5 1.0 50 Resistive or Inductive Load P.C.B. Mounted on 0.2"×0.2" 0.5 25 (5.0mm×5.0mm)Copper Pad Areas 25 50 100 125 150 TL(°C) 0 10 100 Number of Cycles FIG3:Typical Forward Characteristics **FIG4:Typical Reverse Characteristics** <u>A</u> 100 TJ=25℃ Pulse width=300us 1% Duty Cycle Tj=150°C 1000 = Tj=125℃ 10 Tj=100°C ES3A-D ES3F-G 1.0 10 Tj=25℃ 0.1 1.0 0.1 0.01 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 Voltage(%) VF(V) FIG5:Diagram of circuit and Testing wave form of reverse recovery time D trr RL VR T IRR IR

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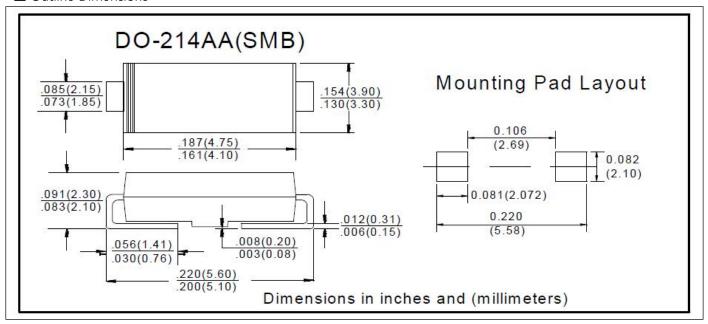


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### ■ Ordering Information (Example)

PREFERED	PACKAGE CODE	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE	
ES3AB~ES3JB	DO-214AC(SMB)	3000	6000	48000	13" reel	

### ■ Outline Dimensions







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